NSN 5961-01-229-7317

Photo Semiconductor Device - Page 1 of 1

View Online at https://aerobasegroup.com/nsn/5961-01-229-7317

Inclosure Material:

Glass

Overall Length:

0.520 inches

Terminal Length:

0.710 inches

Overall Diameter:

1.250 inches

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-36

Response Time:

7.0 nanoseconds

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 forward voltage, dc

Current Rating Per Characteristic:

0.0002 milliamperes peak forward surge current peak

Power Rating Per Characteristic:

0.5 watts small-signal input power, common-collector preset

Special Features:

Junction pattern arrangement: pn

Terminal Type And Quantity:

2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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